

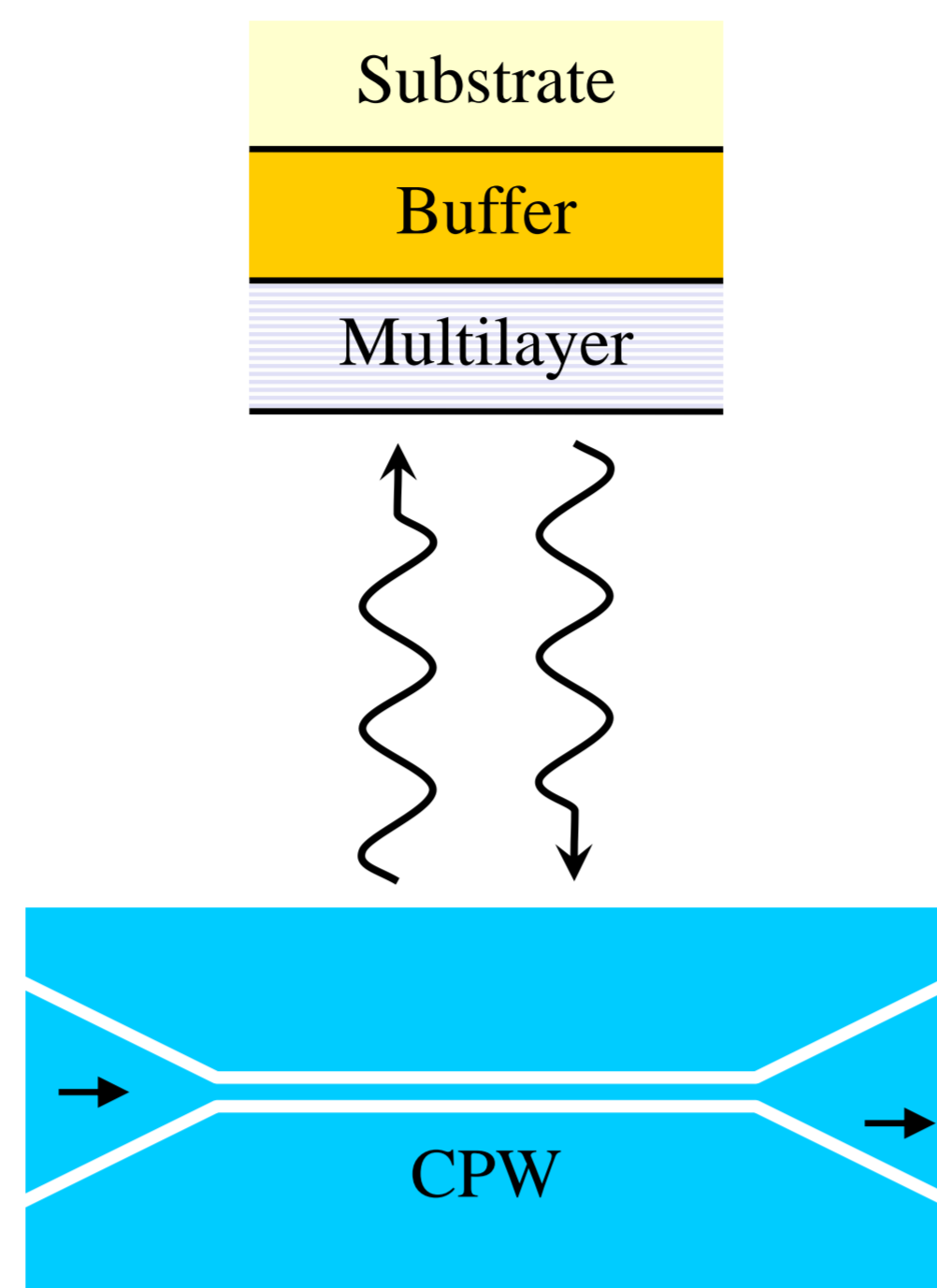
Experimental verification of shielding effect in coplanar waveguide VNA-FMR experiments

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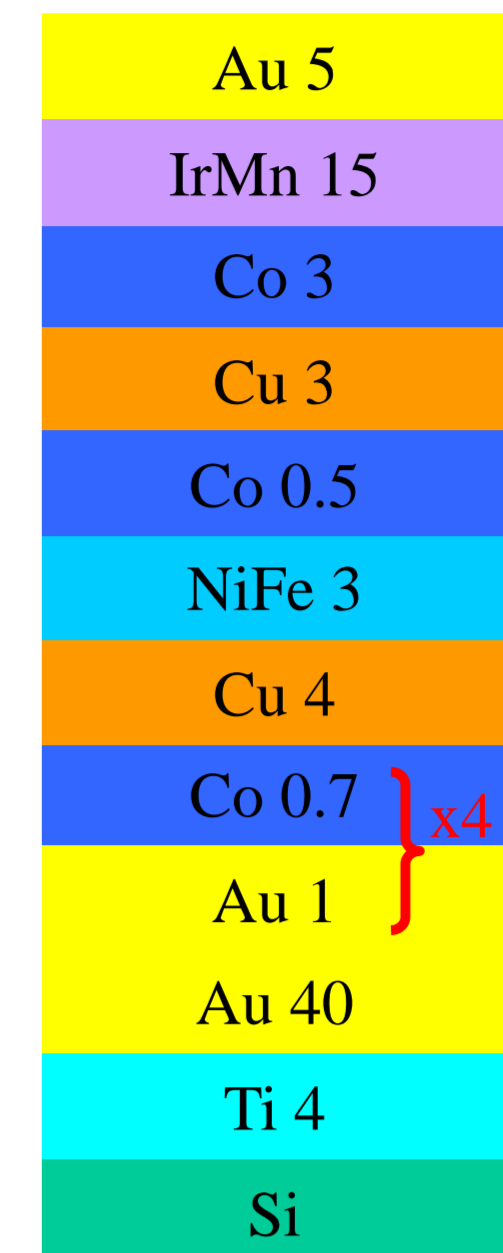
Introduction

Ferromagnetic resonance (FMR) based on VNA and CPW has become a common experimental tool for studying magnetization dynamic of magnetic films and nanostructures. Here we present a new effect of enhancement of the FMR absorption due to a conducting buffer layer, which acts as a shield for microwaves.



Experimental details

- The multilayer films were deposited in a Prevac sputtering system.
- FMR was measured with a Vector Network Analyzer (VNA) on a coplanar waveguide (CPW). Measurements were done at constant microwave frequency.
- The scattering matrix parameter S_{21} was measured in a field-sweep mode.

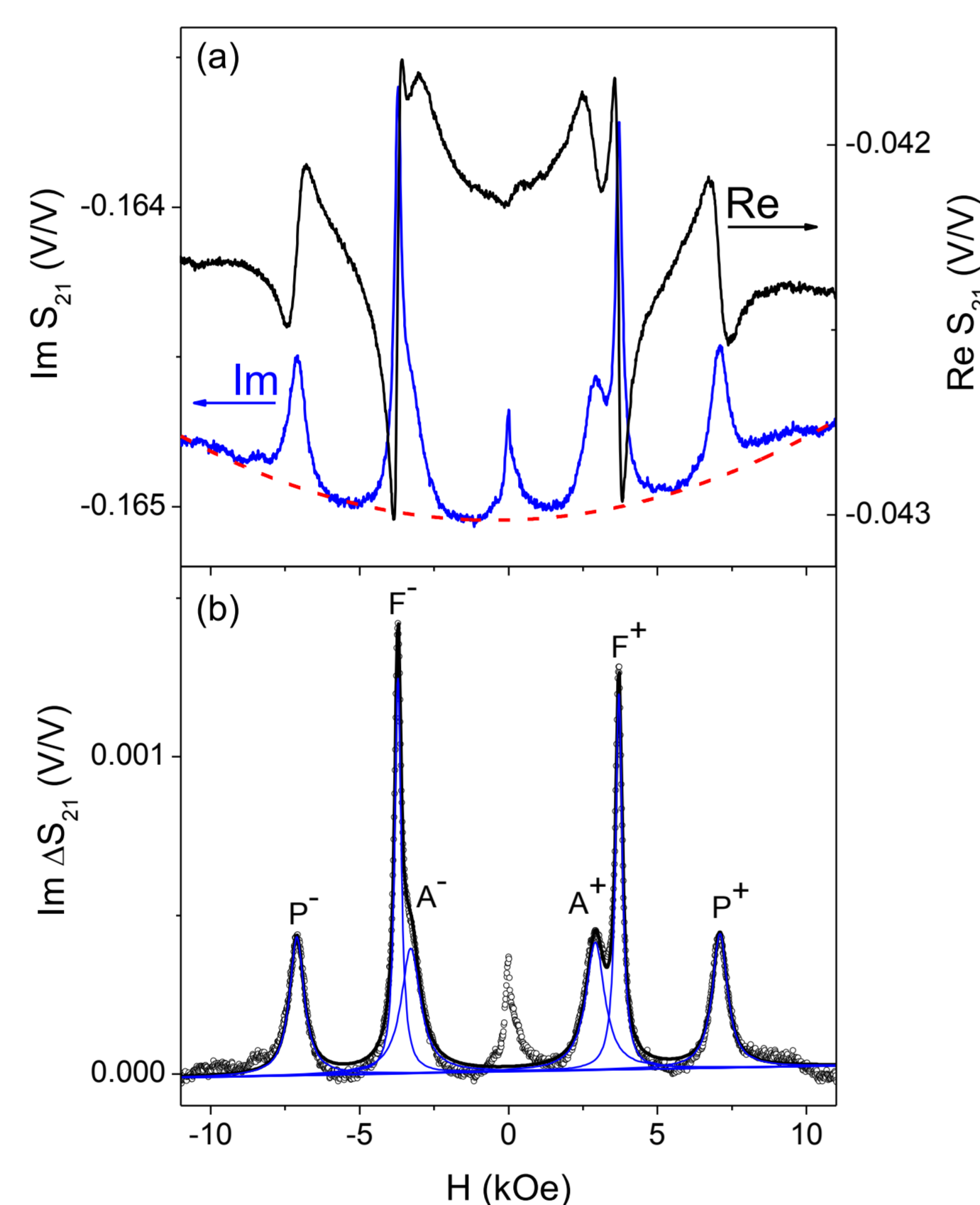


Results

- S_{21} can be separated into magnetic and nonmagnetic contributions assuming that a reflection of microwave power is weak in our VNA-FMR set-up [4].

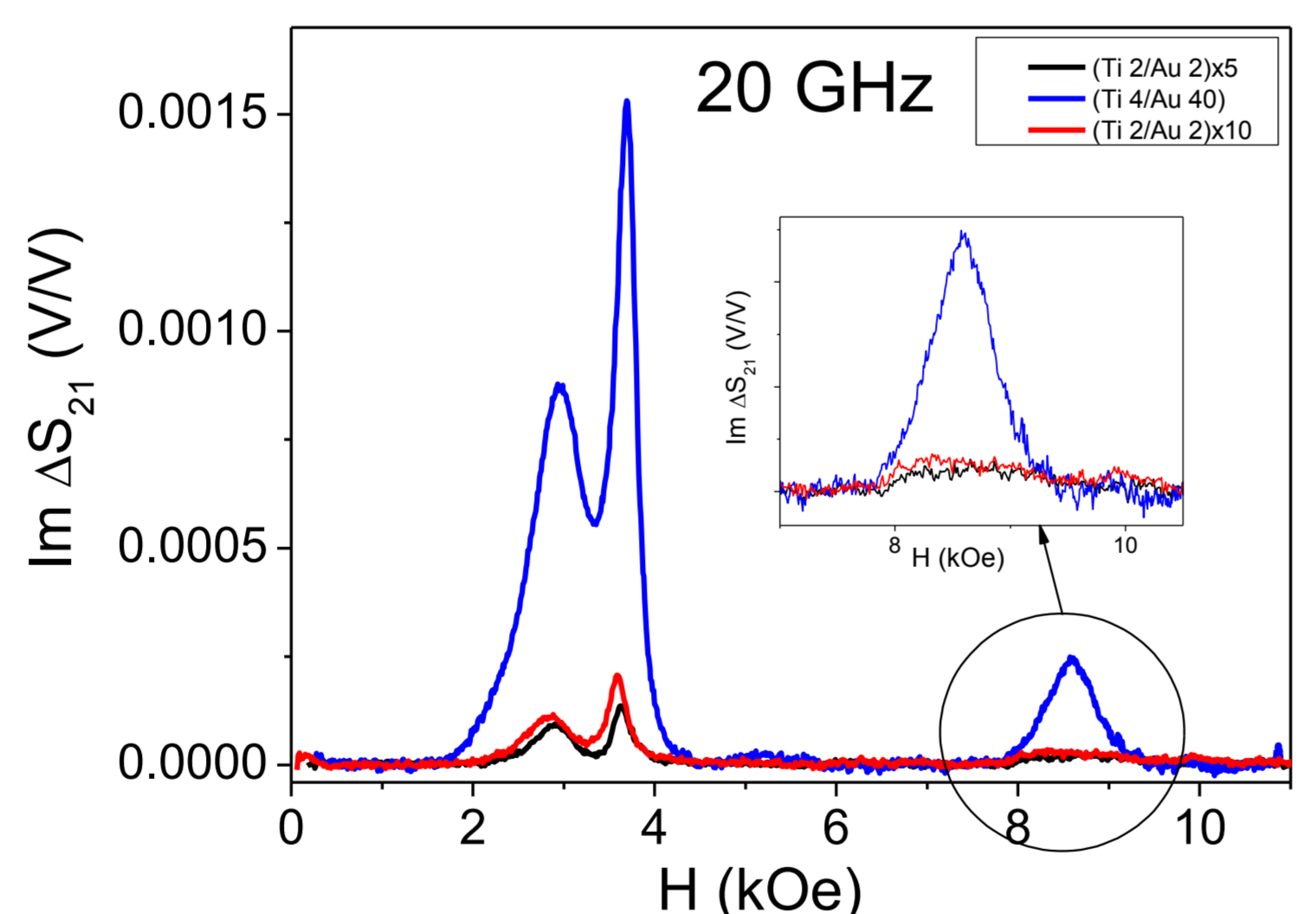
$$S_{21}(H, t) \approx S_{21}^0(H, t) + \frac{\chi(H)}{\chi_0}$$

$$\chi(H) \approx \chi_0 \Delta S_{21}(H)$$



- The multilayer thin films comprise a [Au/Co] \times 4 perpendicular **polarizer**, an in-plane magnetized [Py/Co] **free layer** with Permalloy (Py), and an in-plane Co **analyzer** in contact with IrMn antiferromagnetic layer.

- Figure on the right shows microwave absorption for samples on different buffers, which have **different sheet resistance**.



Summary

- We have shown that the intensity of FMR absorption in the single ultrathin Co layer measured with the use of coplanar waveguide (CPW) depends on the thickness d of the conducting Au buffer $\propto \exp(-d_0/d)$ or, equivalently, on the buffer sheet resistance $\propto \exp(-R/R_0)$.
- These findings are interpreted in terms of the microwave shielding effect by conducting films and an inhomogeneity of the dynamic magnetic field h related to the shielding [1-3]

- Figure (a) shows the enhancement of the signal as a function of copper buffer.

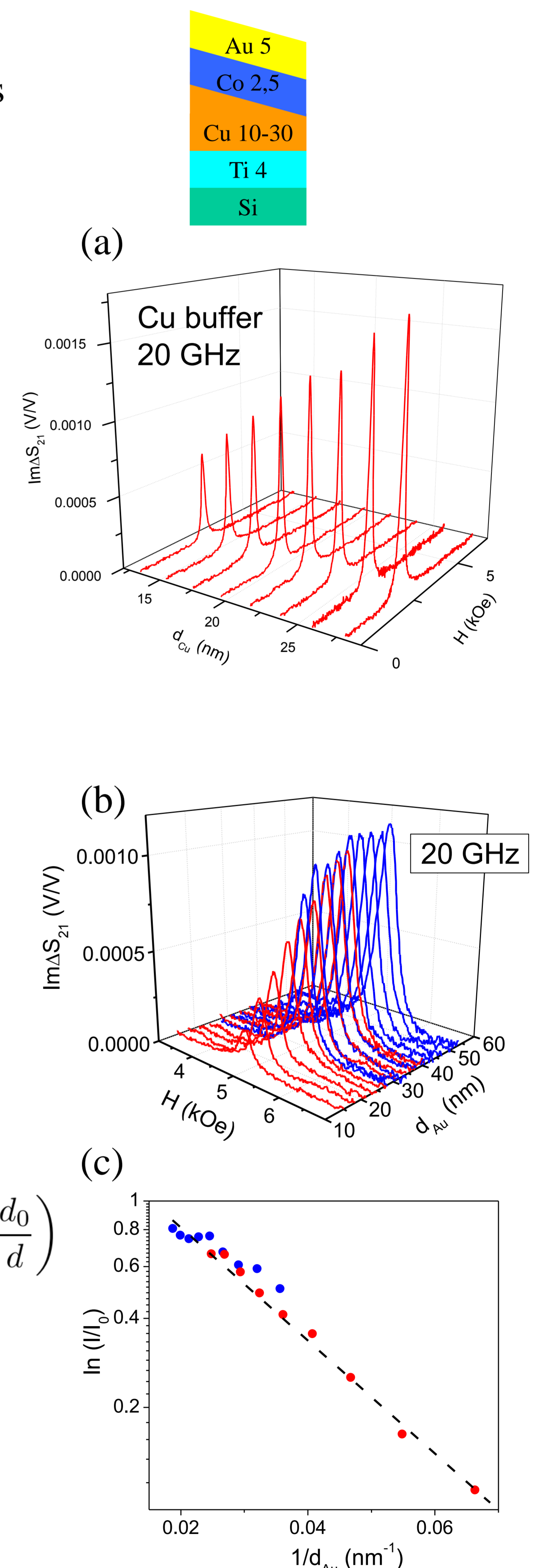
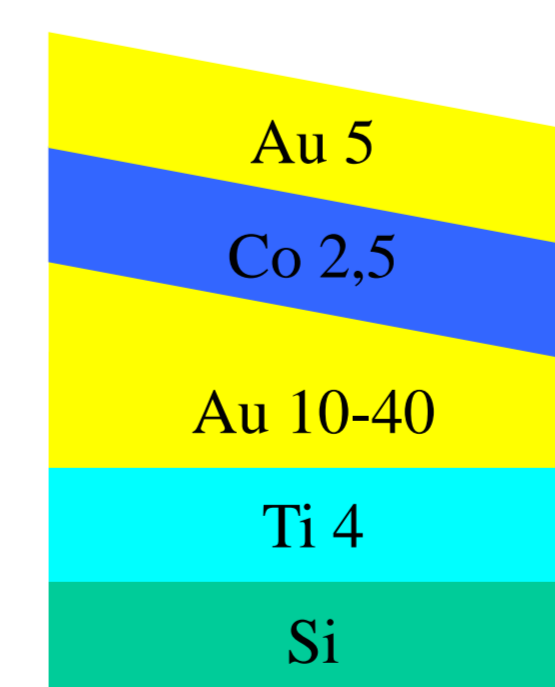
- Figure (b) shows the enhancement of the FMR absorption as a function of the thickness of Au buffer.

- Figure (c) shows that the FMR absorption intensity I is $\propto \exp(-1/\text{buffer thickness})$ or $\propto \exp(-\text{sheet resistance})$

- S_{21} parameter can also be expressed as a function of thickness of conducting layer in proximity of CPW.

$$I \propto e^{-\frac{d_0}{d_{Au}}} = e^{-\frac{R}{R_0}}$$

$$\frac{S_{21}}{S_{21}^0} \propto \exp\left(-\frac{\gamma_0 \rho \delta^2}{2Z_0 w d}\right) \propto \exp\left(-\frac{d_0}{d}\right)$$



References

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Acknowledgment

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